

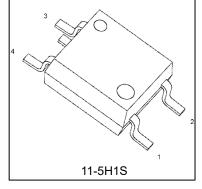
Photocouplers Photorelay

TLP170A

1. Description

The Toshiba TLP170A consists of an infrared emitting diode optically coupled to a photo-MOSFET in a 4-pin SOP package.

This photorelay requires 1 mA of LED current to turn it on. It is suitable for applications that need electrical power savings.



Weight: 0.1 g (typ.)

2. Applications

Mechanical relay replacements Security Equipment Measuring Instruments Factory Automation (FA) Private Branch Exchanges (PBXs)

3. Features

- Package: SOP (2.54SOP4) (Height 2.1 mm, pitch 2.54 mm)
- Normally opened (1-Form-A)
- OFF-state output terminal voltage: 60 V (min)
- Trigger LED current: 1 mA (max)
- ON-state current: 400 mA (max)
- ON-state resistance: 2Ω (max)
- Isolation voltage: 1500 V_{rms} (min)
- Safety standards
 - UL-recognized: UL 1577, File No.E67349
 - cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349

Start of commercial production 2009-06



4. Pin Assignment

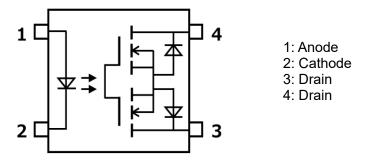


Figure 4.1 Pin Assignment

5. Internal Circuit

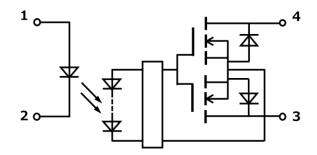


Figure 5.1 Internal Circuit



6. Absolute Maximum Ratings (Note)

 $(T_a = 25^{\circ}C \text{ unless otherwise specified})$

	Characteristics	Symbol	Note	Rating	Unit
LED	Input forward current	I _F		50	mA
	Input forward current derating (T _a ≥ 25 °C)	ΔI _F /ΔT _a		-0.5	mA/°C
	Input reverse voltage	VR		5	V
	Pulse forward current (100 µs pulse, 100 pps)	I _{FP}		1	Α
	Input power dissipation	P _D		50	mW
	Input power dissipation derating (T _a ≥ 25 °C)	$\Delta P_D/\Delta T_a$		-0.5	mW/°C
	Junction temperature	Tj		125	°C
Detector	OFF-state output terminal voltage	Voff		60	V
	ON-state current	I _{ON}		400	mA
	ON-state current derating (T _a ≥ 25 °C)	ΔI _{ON} /ΔT _a		-4.0	mA/°C
	Output power dissipation	Po		300	mW
	Output power dissipation derating (T _a ≥ 25 °C)	ΔΡ _Ο /ΔΤ _a		-3.0	mW/°C
	Junction temperature	Tj		125	°C
Common	Storage temperature	T _{stg}		−55 to 125	°C
	Operating temperature	T _{opr}		−40 to 85	°C
	Lead soldering temperature (10 s)	T _{sol}		260	°C
	Isolation voltage (AC, 60 s, R.H. ≤ 60 %)	BVS	(Note 1)	1500	V_{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature / current / voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc)

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

7. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V_{DD}		_	_	48	V
Input forward current	I _F		_	2	25	mA
ON-state current	Ion		_	_	320	mA
Operating temperature	Topr		-20	_	65	°C

The recommended operating conditions are given as a design guide necessary to obtain Note: the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.



8. Electrical Characteristics

(T_a = 25°C unless otherwise specified)

	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	V _F		I _F = 10 mA	1.0	1.15	1.3	V
	Input reverse current	I _R		V _R = 5 V	_	_	10	μA
	Input capacitance	Ct		V = 0 V, f =1 MHz	_	30	_	pF
Detector	OFF-state current	loff		V _{OFF} = 60 V	_	1	1000	nA
	Output capacitance	Coff		V = 0 V, f =1 MHz	_	130	_	pF

9. Coupled Electrical Characteristics

(T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}		I _{ON} = 400 mA	_	0.4	1	mA
Return LED current	I _{FC}		I _{OFF} = 100 μA	0.1	_	_	mA
ON-state resistance	Ron		I _{ON} = 400 mA, I _F = 2 mA	_	1	2	Ω

10. Isolation Characteristics

(T_a = 25°C unless otherwise specified)

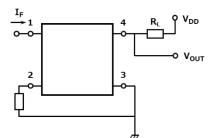
			(2				
Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	(Note 1)	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	(Note 1)	AC, 60 s	1500	_	_	V _{rms}

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

11. Switching Characteristics

(T_a = 25°C unless otherwise specified)

			(1a 20	(ra - 20 O driless otherwise speci				
Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit	
Turn-on time	ton		See Figure 11.1 $R_L = 200 \Omega$, $V_{DD} = 20 V$, $I_F = 2 \text{ mA}$	_	3.0	8.0	ms	
Turn-on time	ton		See Figure 11.1 $R_L = 200 \Omega$, $V_{DD} = 20 V$, $I_F = 5 \text{ mA}$	_	_	5.0		
Turn-off time	toff		See Figure 11.1 $R_L = 200 \Omega$, $V_{DD} = 20 V$, $I_F = 2 \text{ mA}$	_	1.0	3.0		



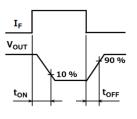


Figure 11.1 Switching Time Test Circuit and Waveform



12. Characteristics Curves and Circuit Connections (Note)

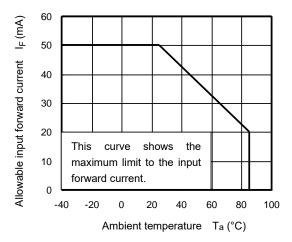


Fig.12.1 $I_F - T_a$

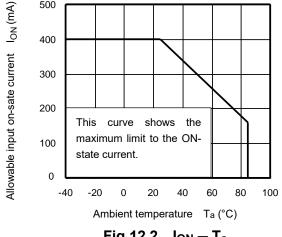


Fig.12.2 $I_{ON} - T_a$

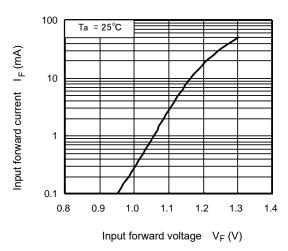


Fig.12.3 If - VF

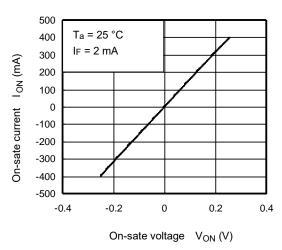


Fig.12.4 Ion — Von

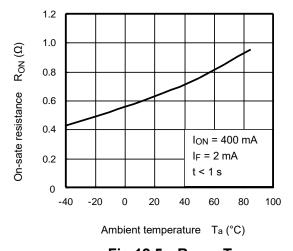


Fig.12.5 Ron - Ta

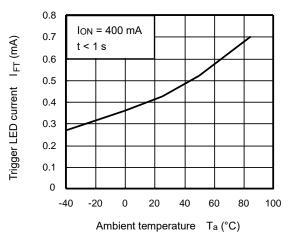
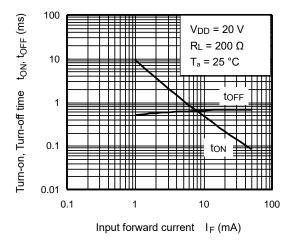


Fig.12.6 I_{FT} - T_a







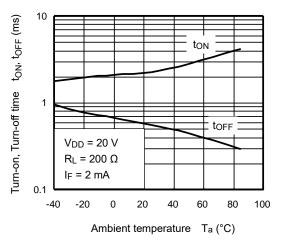


Fig.12.8 t_{ON} , $t_{OFF} - T_a$

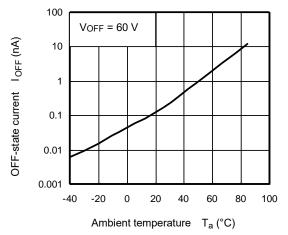


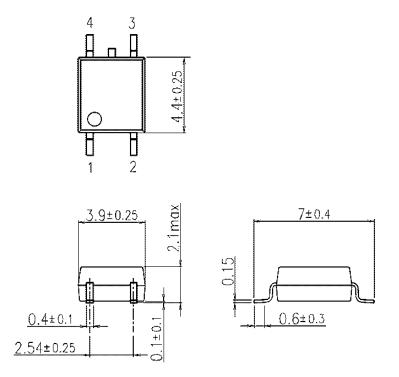
Fig.12.9 I_{OFF} - T_a

The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



13. Package Dimensions

11-5H1S Unit: mm



Weight: 0.1 g (typ.)

Fig. 13.1 Package Dimensions



RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY
 HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN
 LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific
 applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities,
 equipment used in the aerospace industry, and lifesaving and/or life supporting medical equipment. IF YOU USE PRODUCT FOR
 UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or
 contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR
 PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER,
 INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING
 WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2)
 DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR
 INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE,
 ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for
 the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass
 destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations
 including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export
 and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and
 regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please
 use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including
 without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT
 OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

Toshiba Electronic Devices & Storage Corporation

https://toshiba.semicon-storage.com/